

IGBT module

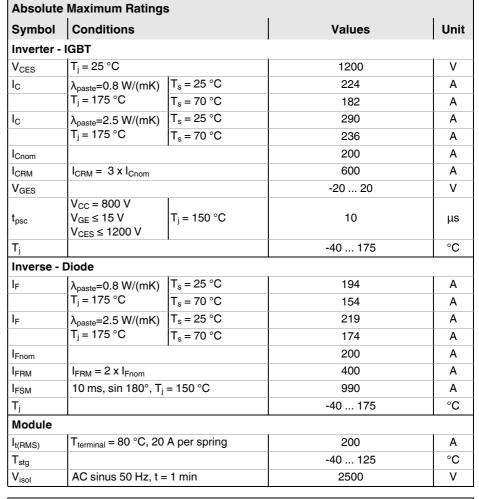
SKiiP 26GB12T4V1

Features

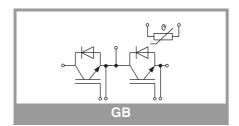
- Trench 4 IGBTs
- Robust and soft freewheeling diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532
- NTC T-Sensor

Remarks

- Max. case temperature limited to T_C= 125°C
- Product reliability results valid for T_j≤150°C (recommended T_{j,op}=-40...+150°C)



Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverter - IGBT										
$\begin{array}{c} V_{CE(sat)} \\ \hline V_{GE} = 15 \ V_{Chiplevel} \end{array}$	_	T _j = 25 °C		1.80	2.05	V				
		T _j = 150 °C		2.20	2.40	V				
V _{CE0}	chiplevel	T _j = 25 °C		0.80	0.90	V				
		T _j = 150 °C		0.70	0.80	V				
r _{CE}	V _{GE} = 15 V chiplevel	T _j = 25 °C		5.0	5.8	mΩ				
		T _j = 150 °C		7.5	8.0	mΩ				
$V_{GE(th)}$	$V_{GE} = V_{CE}$, $I_C = 12 \text{ mA}$		5	5.8	6.5	V				
I _{CES}	$V_{GE} = 0 \text{ V}, V_{CE} = 12$	00 V, T _j = 25 °C		0.1	0.3	mA				
C _{ies}	V _{CE} = 25 V V _{GE} = 0 V	f = 1 MHz		12.30		nF				
C _{oes}		f = 1 MHz		0.81		nF				
C _{res}		f = 1 MHz		0.69		nF				
Q_{G}	V _{GE} = - 8 V+ 15 V			1130		nC				
R _{Gint}	T _j = 25 °C			3.8		Ω				
t _{d(on)}	$\begin{aligned} &I_C=200~\text{A}\\ &R_{G~on}=2~\Omega\\ &R_{G~off}=2~\Omega\\ &\text{di/dt}_{on}=5500~\text{A/}\mu\text{s}\\ &\text{di/dt}_{off}=2000~\text{A/}\mu\text{s} \end{aligned}$	T _j = 150 °C		170		ns				
t _r		T _j = 150 °C		45		ns				
E _{on}		T _j = 150 °C		13.6		mJ				
$t_{d(off)}$		T _j = 150 °C		440		ns				
t _f			91			ns				
E _{off}	du/dt = $7000 \text{ V/}\mu\text{s}$ V_{GE} = $+15$ /- 15 V L_s = 25 nH	T _j = 150 °C		22.1		mJ				
R _{th(j-s)}	per IGBT, λ _{paste} =0.8 W/(mK)			0.25		K/W				
R _{th(j-s)}	per IGBT, λ _{paste} =2.5 W/(mK)			0.16		K/W				





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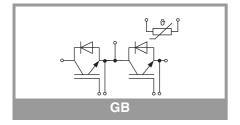
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Characteristics										
Symbol	Conditions	min.	typ.	max.	Unit					
Inverse - Diode										
$V_F = V_{EC}$	I _F = 200 A	T _j = 25 °C		2.20	2.52	٧				
	V _{GE} = 0 V chiplevel	T _j = 150 °C		2.15	2.47	V				
V _{F0}	chiplevel	T _j = 25 °C		1.30	1.50	V				
		T _j = 150 °C		0.90	1.10	V				
r _F	chiplevel	T _j = 25 °C		4.5	5.1	mΩ				
ľ	Chipievei	T _j = 150 °C		6.3	6.9	mΩ				
I _{RRM}	$I_F = 200 \text{ A}$ $di/dt_{off} = 5215 \text{ A/}\mu\text{s}$ $V_{GE} = -15 \text{ V}$ $V_{CC} = 600 \text{ V}$	T _j = 150 °C		228		Α				
Q_{rr}		T _j = 150 °C		32		μC				
E _{rr}		T _j = 150 °C		13.4		mJ				
R _{th(j-s)}	per Diode, λ _{paste} =0.8 W/(mK)			0.34		K/W				
R _{th(j-s)}	per Diode, λ _{paste} =2.5 W/(mK)			0.28		K/W				
Module										
L _{CE}				20		nΗ				
Ms	to heat sink		2		2.5	Nm				
w				50		g				
Temperature Sensor										
R ₁₀₀	T_c =100°C (R ₂₅ =5 kΩ)		493 ± 5%			Ω				
B _{25/85}	$R_{(T)} = R_{25} * \exp[B_{25/85} * (1/T-1/298)], [T] = K$			3420		K				



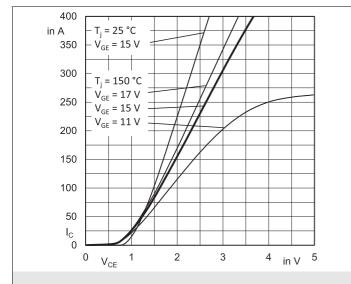


Fig. 1: Typ. output characteristic, inclusive R_{CC'+ EE'}

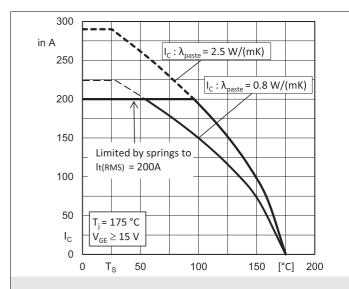


Fig. 2: Rated current vs. temperature $I_C = f(T_S)$

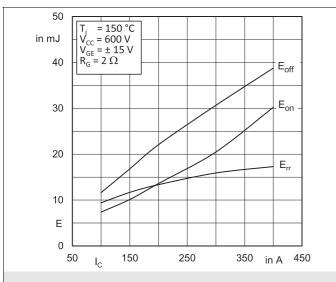


Fig. 3: Typ. turn-on /-off energy = $f(I_C)$

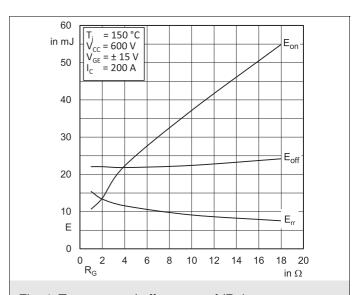


Fig. 4: Typ. turn-on /-off energy = $f(R_G)$

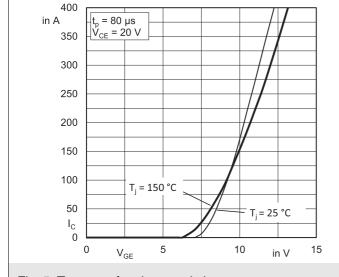


Fig. 5: Typ. transfer characteristic

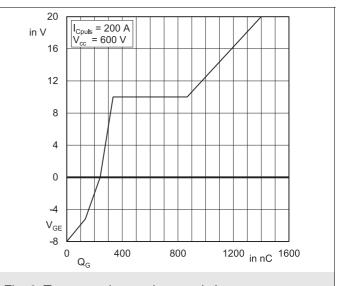


Fig. 6: Typ. gate charge characteristic

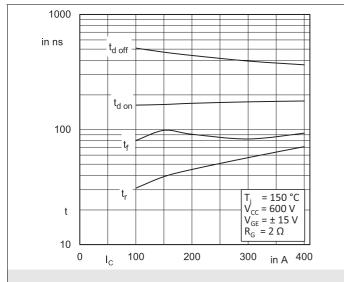


Fig. 7: Typ. switching times vs. I_C

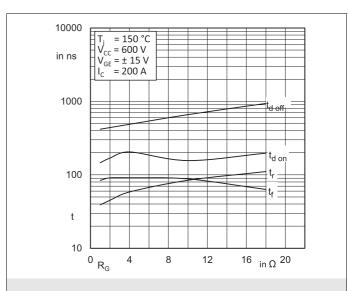


Fig. 8: Typ. switching times vs. gate resistor R_{G}

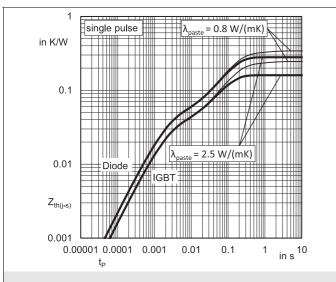


Fig. 9: Transient thermal impedance of IGBT and Diode

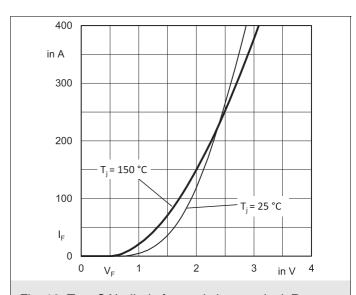


Fig. 10: Typ. CAL diode forward charact., incl. R_{CC'+ EE'}

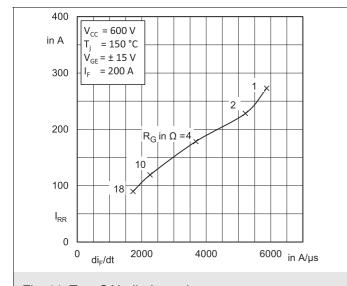


Fig. 11: Typ. CAL diode peak reverse recovery current

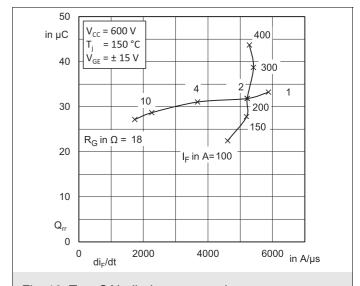
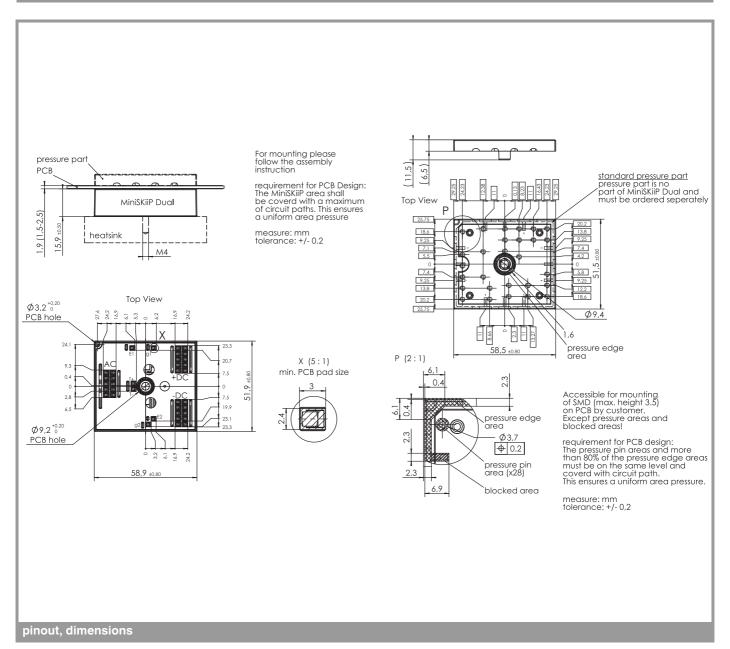
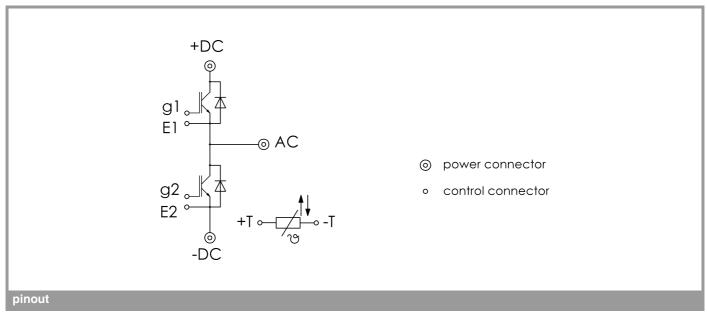


Fig. 12: Typ. CAL diode recovery charge





This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, chapter IX.

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